

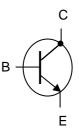
NPN 2N3439 - 2N3440

HIGH VOLTAGE TRANSISTOR

The 2N3439 and 2N3440 are high voltage silicon epitaxial transistors mounted in TO-39 metal package.

They are intended for use in power amplifier, in consumer and industrial line-operated applications.

These devices are particularity suited as drives in high voltage low current inverters, switching and series regulators. Compliance to RoHS.



ABSOLUTE MAXIMUM RATINGS

| Symbol | Potingo | | Va | l lmit | | |
|------------------|---------------------------|-------------------------|--------|--------|------|--|
| Symbol | Ratings | | 2N3439 | 2N3440 | Unit | |
| V _{CEO} | Collector-Emitter Voltage | $I_B = 0$ | 350 | 250 | V | |
| V _{CBO} | Collector-Base Voltage | $I_E = 0$ | 450 | 300 | V | |
| V _{EBO} | Emitter-Base Voltage | $I_C = 0$ | 7 | | V | |
| Ic | Collector Current | | 1 | | Α | |
| I _B | Base Current | | 500 | | mA | |
| В | Total Power Dissipation | $T_{amb} = 25^{\circ}$ | | 1 | _ w | |
| P _D | Total Fower Dissipation | $T_{case} = 25^{\circ}$ | 1 | 0 | ¬ | |
| T_{J} | Junction Temperature | | 20 | 00 | °C | |
| T _{Stg} | Storage Temperature rar | nge | -65 to | +200 | | |

THERMAL CHARACTERISTICS

| Symbol | Ratings | Value | Unit |
|--------------------|---|-------|------|
| R _{thJ-a} | Thermal Resistance, Junction to ambient | 175 | °C/W |
| R _{thJ-c} | Thermal Resistance, Junction to case | 35 | °C/W |



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ELECTRICAL CHARACTERISTICS

Tj=25°C unless otherwise specified

| Symbol | Ratings | Test Condition(s) | | Min | Тур | Max | Unit |
|----------------------|--|--|------------------|----------|-----|-----|------|
| I _{CBO} | Collector Cutoff | $V_{CB} = 360 \text{ V}, I_E = 0$ | 2N3439 | _ | - | 20 | μA |
| | Current Collector Cutoff | $V_{CB} = 250 \text{ V}, I_{E} = 0$ $V_{CE} = 300 \text{ V}, I_{B} = 0$ | 2N3440 2N3439 | _ | - | 20 | - |
| I _{CEO} | Current | $V_{CE} = 200 \text{ V}, I_{B} = 0$ | 2N3440 | - | - | 50 | μA |
| I _{CEX} | Collector Cutoff | $V_{CE} = 450 \text{ V}, V_{BE} = -1.5 \text{ V}$ | 2N3439 | _ | - | 500 | μА |
| -GLX | Current | $V_{CE} = 300 \text{ V}, V_{BE} = -1.5 \text{ V}$ | 2N3440 | <u> </u> | | | |
| I _{EBO} | Emitter Cutoff Current | $V_{BE} = 6 \text{ V}, I_{C} = 0$ | 2N3439 2N3440 | _ | - | 20 | μΑ |
| V _{CEO} | Collector-emitter | L = 50 m \ L = 0 | 2N3439 | 350 | 1 | - | V |
| ▼ CEO | Breakdown Voltage $I_C = 50 \text{ mA}, I_B = 0$ | IC = 50 IIIA, IB = 0 | 2N3440 | 250 | ı | - | V |
| | | $I_C = 2 \text{ mA}, V_{CE} = 10 \text{ V}$ | 2N3439 | 30 | - | - | |
| h _{FE} C | DC Current Gain | $I_C = 20 \text{ mA}, V_{CE} = 10 \text{ V}$ | 2N3439 2N3440 | 40 | - | 160 | - |
| V _{CE(SAT)} | Collector-Emitter saturation Voltage | $I_C = 50 \text{ mA}, I_B = 4 \text{ mA}$ | | - | ı | 0.5 | V |
| V _{BE(SAT)} | Base-Emitter saturation Voltage | $I_C = 50 \text{ mA}, I_B = 4 \text{ mA}$ | | - | ı | 1.3 | V |
| f _T | Transition frequency | $I_C = 10 \text{ mA}, V_{CB} = 10 \text{ V}$ f = 5 MHz | | 15 | - | - | MHz |
| C _{ob} | Output Capacitance | V _{CB} = 10 V, f = 1MHz | | - | - | 10 | pF |

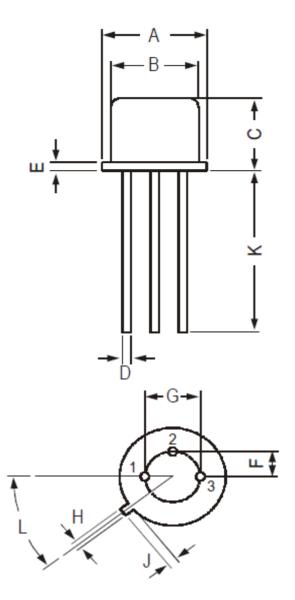


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MECHANICAL DATA CASE TO-39

| DIME | DIMENSIONS (mm) | | |
|------|-----------------|------|--|
| | min | max | |
| А | 8.50 | 9.39 | |
| В | 7.74 | 8.50 | |
| С | 6.09 | 6.60 | |
| D | 0.40 | 0.53 | |
| Е | - | 0.88 | |
| F | 2.41 | 2.66 | |
| G | 4.82 | 5.33 | |
| Н | 0.71 | 0.86 | |
| J | 0.73 | 1.02 | |
| K | 12.70 | - | |
| L | 42° | 48° | |

| Emitter | Pin 1 : |
|-----------|---------|
| Base | Pin 2 : |
| Collector | Pin 3 : |
| Collector | Case : |



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